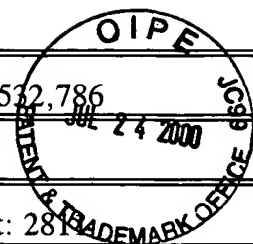


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Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
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_____	AB					
_____	AC					
_____	AD					
_____	AE					

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<u>TN</u>	AK	"Low-Noise AlGaAs Lasers Grown by Organo-Metallic Vapor Phase Epitaxy", <u>IEEE Journal of Quantum Electronics</u> , Vol. 25, No. 6 (June 1989), pp. 1483-1488.
<u>TN</u>	AL	"A Theoretical Analysis of Self-Sustained Pulsation Phenomena in Narrow-Stripe Semiconductor Lasers", <u>IEEE Journal of Quantum Electronics</u> , Vol. 29, No. 5 (May 1993), pp. 1330-1336.

Examiner	<i>Phan N. Nguyen</i>	Date Considered	<i>7-9-02</i>
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